



Product Specification

Surge Type

MBR1060CTG/MBRF1060CTG

Construction : Schottky Barrier Rectifier

Application : For General Purpose

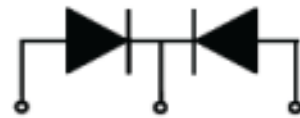
(Manufacturer) :

Surge Components Inc

Prepared on Sep. 17th, 2008

Prepared: R & D Department

Approval: QRA Department



1. Anode 2. Cathode 3. Anode

SCHOTTKY BARRIER RECTIFIER

10 AMPERES

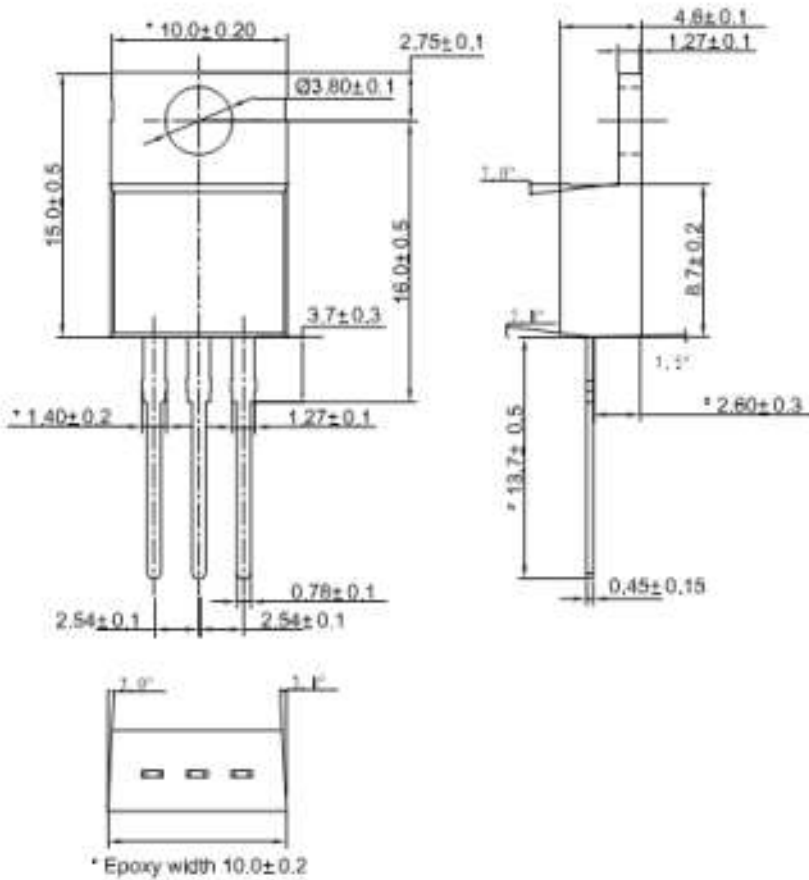
60VOLTS

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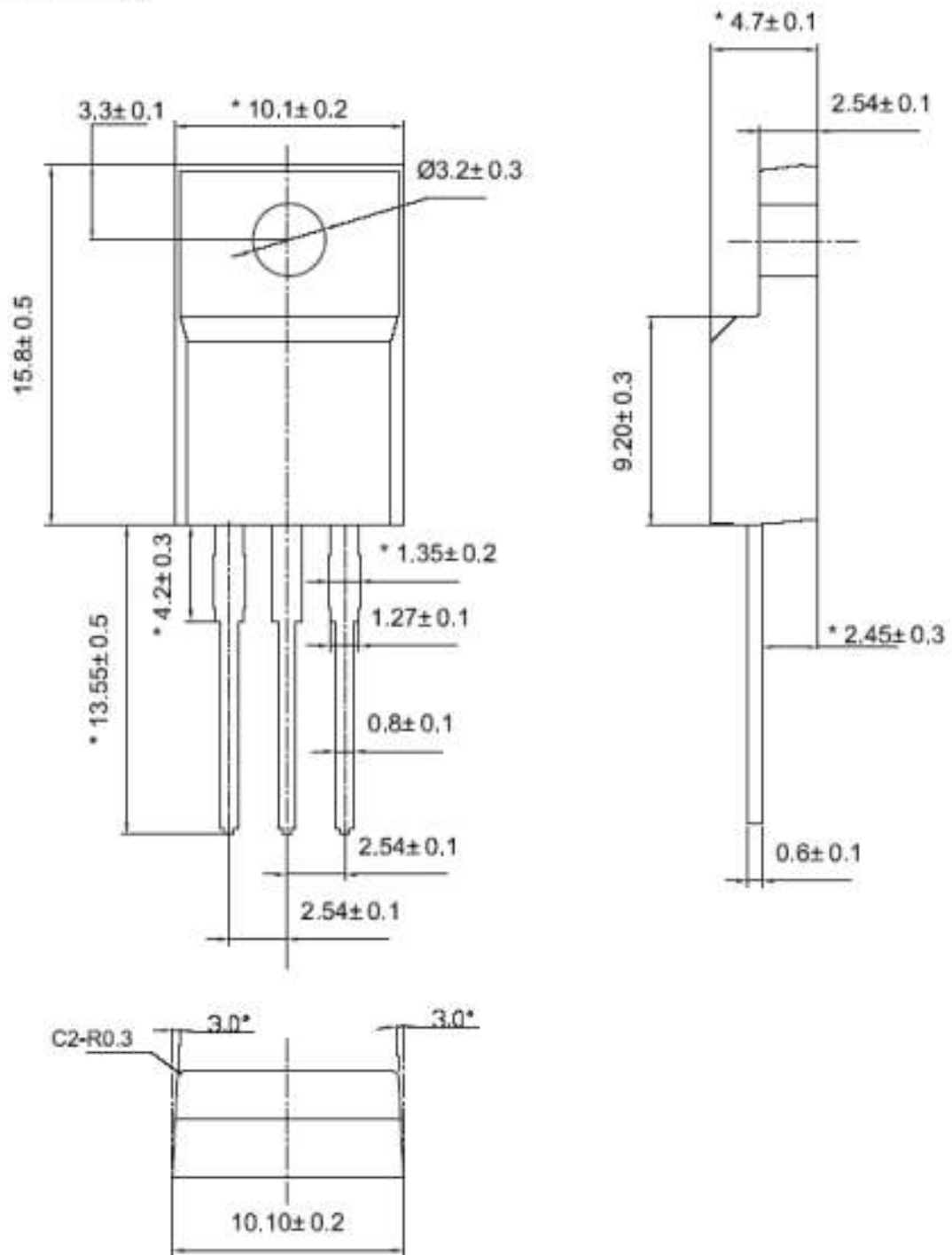
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6. Packing Specification PACKAGING SPECIFICATION
7. Description of Box Label

1. Package Outline (TO220-AB)

UNIT:mm

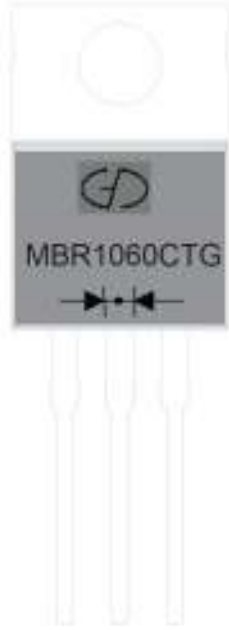


Package Outline (TO220F-AB)



Lead Frame Material : Copper Plating: Pure Tin Plating

2. MARKING



1. Part Name : MBR1060CTG(TO220AB)
MBRF1060CTG(TO220F-AB)

2. Logo Mark: 

3. Polarity : 

3.Features& Mechanical Characteristics Features

- Plastic package has underwriters Laboratory Flammability Classification 94V-0
- Dual rectifier construction, positive center tap
- Metal of silicon rectifier, majority carrier conduction
- Low forward voltage, high efficiency
- Guarding for over voltage protection
- For use in low voltage, high frequency inverters,
- Free wheeling, and polarity protection applications

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 1.9grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max.for10 sec
- Shipped 50 units per plastic tube

4.Maximum Ratings and Electrical Characteristics

MAXIMUM RATINGS and ELECTRICAL CHARACTERISTICS(TC=25°C unless otherwise moted)					
PARAMETER	TEST CONDITIONS		SYMBOL	MBR(F)1060CT	UNIT
Maximum repetitive peak reverse voltage			VRRM	60	V
Working peak reverse voltage			VRWM	60	V
Maximum DC blocking voltage			VDC	60	V
Maximum average forward rectified current at Tc=105°C total device per diode			IF(AV)	5 10	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode			IFSM	150	A
Peak repetitive reverse current per leg at tp=2.0us , 1KHz			IRRM	0.5	A
Voltage rate of change (rated VR)			DV/dt	10000	V/us
Operating junction temperature range			TJ	-55 to+150	°C
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 sec			VAC	1500	V
Storage temperature range			TSTG	-55 to+150	°C
Maximum instantaneous forward voltage per leg	IF=5A	Tc=25°C	VF	0.80	V
	IF=10A	Tc=25°C		0.90	
Maximum reverse current per leg at working peak Reverse voltage	TJ=25°C TJ=100°C		IR	200 10	uA mA

Thermal Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Type (TO220)	Type (TO220F)	Unit
RθJC	Thermal Resistance, Junction to Case per Leg	2.0	4.0	°C /W
RθJA	Thermal Resistance, Junction to Ambient per Leg	62.5	62.5	°C /W

Note:

1. Screw mounting with 4-40 screw, where washer diameter is ≤4.9mm(0.19")
2. Pulse test:300us pulse width,1% duty cycle

5. Rating and Characteristic Curves

(TA = 25 °C unless otherwise noted)

Rating and Characteristic Curves

(Tc=25°C unless otherwise noted)

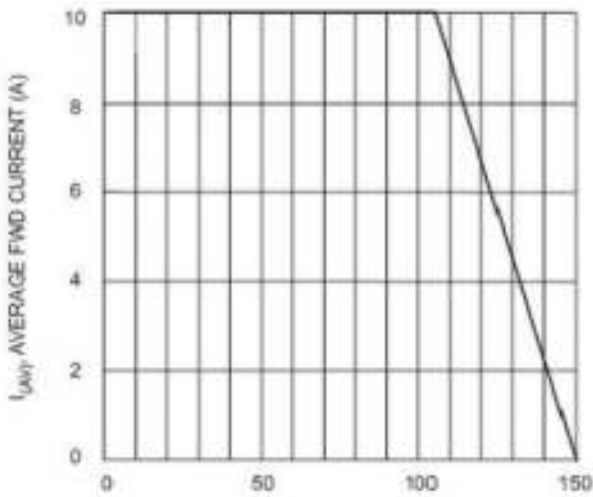


Fig. 1 Forward Current Derating Curve

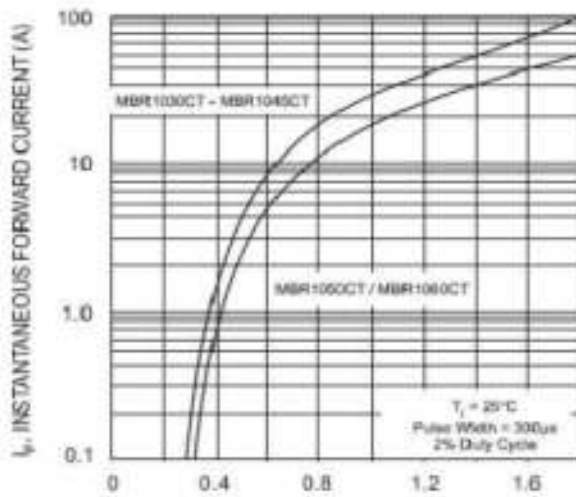


Fig. 2 Typical Forward Characteristics

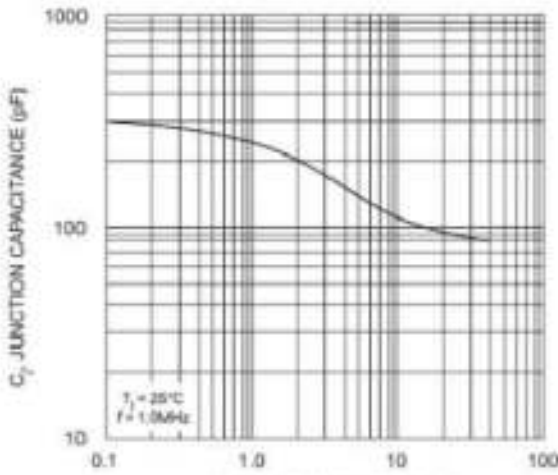


Fig. 4 Typical Junction Capacitance

